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## 200MHz Amplifiers

The EL5150, EL5151, EL5250, EL5251, and EL5451 are 200 MHz bandwidth -3 dB voltage mode feedback amplifiers with DC accuracy of $0.01 \%, 1 \mathrm{mV}$ offsets and $10 \mathrm{kV} / \mathrm{V}$ open loop gains. These amplifiers are ideally suited for applications ranging from precision measurement instrumentation to high speed video and monitor applications. Capable of operating with as little as 1.4 mA of current from a single supply ranging from 5 V to 12 V , dual supplies ranging from $\pm 2.5 \mathrm{~V}$ to $\pm 5.0 \mathrm{~V}$, these amplifiers are also well suited for handheld, portable and battery-powered equipment.

Single amplifiers are offered in SOT-23 packages and duals in a 10 Ld MSOP package for applications where board space is critical. Quad amplifiers are available in a 14 Ld SOIC package. Additionally, singles and duals are available in the industry-standard 8 Ld SOIC package. All parts operate over the industrial temperature range of $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$.

## Features

- 200MHz -3dB bandwidth
- $67 \mathrm{~V} / \mu$ s slew rate
- Very high open loop gains 50kV/V
- Low supply current $=1.4 \mathrm{~mA}$
- Single supplies from 5 V to 12 V
- Dual supplies from $\pm 2.5 \mathrm{~V}$ to $\pm 5 \mathrm{~V}$
- Fast disable on the EL5150 and EL5250
- Low cost
- Pb-free available (RoHS compliant)


## Applications

- Imaging
- Instrumentation
- Video
- Communications devices


## Pinouts



EL5250 (10 LD MSOP) TOP VIEW


EL5150
(6 LD SOT-23)
TOP VIEW


EL5251
(8 LD MSOP) TOP VIEW


EL5151
(5 LD SOT-23)
TOP VIEW


EL5451
(14 LD SOIC) TOP VIEW


## Ordering Information

| PART NUMBER | PART MARKING | PACKAGE | PKG. DWG. \# |
| :---: | :---: | :---: | :---: |
| EL5150IS | 5150IS | 8 Ld SOIC | MDP0027 |
| EL5150IS-T7* | 5150IS | 8 Ld SOIC (Tape and Reel) | MDP0027 |
| EL5150IS-T13* | 5150IS | 8 Ld SOIC (Tape and Reel) | MDP0027 |
| EL5150ISZ (Note) | 5150ISZ | 8 Ld SOIC (Pb-free) | MDP0027 |
| EL5150ISZ-T7* (Note) | 5150ISZ | 8 Ld SOIC (Tape and Reel) (Pb-free) | MDP0027 |
| EL5150ISZ-T13* (Note) | 5150ISZ | 8 Ld SOIC (Tape and Reel) (Pb-free) | MDP0027 |
| EL5150IW-T7* | BEAA | 6 Ld SOT-23 (Tape and Reel) | MDP0038 |
| EL5150IW-T7A* | BEAA | 6 Ld SOT-23 (Tape and Reel) | MDP0038 |
| EL5150IWZ-T7* (Note) | BAAJ | 6 Ld SOT-23 (Tape and Reel) (Pb-free) | MDP0038 |
| EL5150IWZ-T7A* (Note) | BAAJ | 6 Ld SOT-23 (Tape and Reel) (Pb-free) | MDP0038 |
| EL5151IW-T7* | BFAA | 5 Ld SOT-23 (Tape and Reel) | MDP0038 |
| EL5151IW-T7A* | BFAA | 5 Ld SOT-23 (Tape and Reel) | MDP0038 |
| EL5151IWZ-T7* (Note) | BAAK | 5 Ld SOT-23 (Tape and Reel) (Pb-free) | MDP0038 |
| EL5151IWZ-T7A* (Note) | BAAK | 5 Ld SOT-23 (Tape and Reel) (Pb-free) | MDP0038 |
| EL52501Y | BAEAA | 10 Ld MSOP | MDP0043 |
| EL5250IY-T7* | BAEAA | 10 Ld MSOP (Tape and Reel) | MDP0043 |
| EL5250IY-T13* | BAEAA | 10 Ld MSOP (Tape and Reel) | MDP0043 |
| EL5251IS | 5251IS | 8 Ld SOIC | MDP0027 |
| EL5251IS-T7* | 5251IS | 8 Ld SOIC (Tape and Reel) | MDP0027 |
| EL5251IS-T13* | 5251IS | 8 Ld SOIC (Tape and Reel) | MDP0027 |
| EL5251ISZ (Note) | 5251ISZ | 8 Ld SOIC (Pb-free) | MDP0027 |
| EL5251ISZ-T13* (Note) | 5251ISZ | 8 Ld SOIC (Tape and Reel) (Pb-free) | MDP0027 |
| EL5251ISZ-T7* (Note) | 5251ISZ | 8 Ld SOIC (Tape and Reel) (Pb-free) | MDP0027 |
| EL5251IY | BAFAA | 8 Ld MSOP | MDP0043 |
| EL5251IY-T7* | BAFAA | 8 Ld MSOP (Tape and Reel) | MDP0043 |
| EL5251IY-T13* | BAFAA | 8 Ld MSOP (Tape and Reel) | MDP0043 |
| EL5251IYZ (Note) | BBBHA | 8 Ld MSOP (Pb-free) | MDP0043 |
| EL5251IYZ-T13* (Note) | BBBHA | 8 Ld MSOP (Tape and Reel) (Pb-free) | MDP0043 |
| EL5251IYZ-T7* (Note) | BBBHA | 8 Ld MSOP (Tape and Reel) (Pb-free) | MDP0043 |
| EL5451IS | 5451IS | 14 Ld SOIC | MDP0027 |
| EL5451IS-T7* | 5451IS | 14 Ld SOIC (Tape and Reel) | MDP0027 |
| EL5451IS-T13* | 5451IS | 14 Ld SOIC (Tape and Reel) | MDP0027 |
| EL5451ISZ (Note) | 5451ISZ | 14 Ld SOIC (Pb-free) | MDP0027 |
| EL5451ISZ-T7* (Note) | 5451ISZ | 14 Ld SOIC (Tape and Reel) (Pb-free) | MDP0027 |
| EL5451ISZ-T13* (Note) | 5451ISZ | 14 Ld SOIC (Tape and Reel) (Pb-free) | MDP0027 |

*Please refer to TB347 for details on reel specifications.
NOTE: These Intersil Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and $100 \%$ matte tin plate PLUS ANNEAL - e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

EL5150, EL5151, EL5250, EL5251, EL5451

| Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ ) |  |
| :---: | :---: |
| Supply Voltage between $\mathrm{V}_{S}$ and $\mathrm{V}_{\mathrm{S}}$ | 13.2 V |
| Slewrate of Voltage between $\mathrm{V}_{\mathrm{S}}$ and $\mathrm{V}_{\mathrm{S}}$ | 1V/ $/ \mathrm{s}$ |
| Maximum Continuous Output Current | 40mA |
| Pin Voltages | GND - 0.5 V to $\mathrm{V}_{\mathrm{S}}+0.5 \mathrm{~V}$ |
| Current into $\mathrm{I}_{\mathrm{N}^{+}}, \mathrm{I}_{\mathrm{N}^{-}}, \mathrm{CE}$ |  |

Supply Voltage between $\mathrm{V}_{\mathrm{S}}$ and $\mathrm{V}_{\mathrm{S}}$. . . . . . . . . . . . . . . . . . . . . 13.2V
Slewrate of Voltage between $\mathrm{V}_{\mathrm{S}}$ and $\mathrm{V}_{\mathrm{S}}$. . . . . . . . . . . . . . . . . $1 \mathrm{~V} / \mu \mathrm{s}$
Pin Voltages. . . . . . . . . . . . . . . . . . . . . . . . GND -0.5 V to $\mathrm{V}_{\mathrm{S}}+0.5 \mathrm{~V}$


## Thermal Information

Junction Temperature . . . . . . . . . . . . . . . . . . . . . . . $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
Storage Temperature . . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Ambient Operating Temperature . . . . . . . . . . . . . . . . . $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Power Dissipation . . . . . . . . . . . . . . . . . . . . . . . . . . . . . See Curves
Pb-Free Reflow Profile. . . . . . . . . . . . . . . . . . . . . . . . see link below http://www.intersil.com/pbfree/Pb-FreeReflow.asp

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_{J}=T_{C}=T_{A}$

Electrical Specifications $\quad \mathrm{V}_{\mathrm{S}^{+}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}^{-}}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=150 \Omega, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.

| PARAMETER | DESCRIPTION | CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| AC PERFORMANCE |  |  |  |  |  |  |
| BW | -3dB Bandwidth | $A_{V}=+1, R_{L}=500 \Omega$ |  | 200 |  | MHz |
|  |  | $A_{V}=+2, R_{L}=150 \Omega$ |  | 40 |  | MHz |
| GBWP | Gain Bandwidth Product | $A_{V}=500$ |  | 40 |  | MHz |
| BW1 | 0.1 dB Bandwidth | $A_{V}=+1, R_{L}=500 \Omega$ |  | 10 |  | MHz |
| SR | Slew Rate | $\mathrm{V}_{\mathrm{O}}= \pm 2.5 \mathrm{~V}, \mathrm{~A}_{\mathrm{V}}=+2$ | 50 | 67 |  | V/us |
|  |  | $\mathrm{V}_{\mathrm{O}}= \pm 3.0 \mathrm{~V}, \mathrm{~A}_{\mathrm{V}}=1, \mathrm{R}_{\mathrm{L}}=500 \Omega$ |  | 100 |  | V/us |
| ts | 0.1\% Settling Time | $\mathrm{V}_{\text {OUT }}=-1 \mathrm{~V}$ to $+1 \mathrm{~V}, \mathrm{~A}_{\mathrm{V}}=-2$ |  | 80 |  | ns |
| dG | Differential Gain Error (Note 1) | $A_{V}=+2, R_{L}=150 \Omega$ |  | 0.04 |  | \% |
| dP | Differential Phase Error (Note 1) | $A_{V}=+2, R_{L}=150 \Omega$ |  | 0.9 |  | - |
| $\mathrm{V}_{\mathrm{N}}$ | Input Referred Voltage Noise |  |  | 12 |  | $\mathrm{nV} / \sqrt{ } \mathrm{Hz}$ |
| ${ }^{\prime} \mathrm{N}$ | Input Referred Current Noise |  |  | 1.0 |  | $\mathrm{pA} / \sqrt{ } \mathrm{Hz}$ |
| DC PERFORMANCE |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OS }}$ | Offset Voltage |  | -1 | 0.5 | 1 | mV |
| $\mathrm{T}_{\mathrm{C}} \mathrm{V}_{\text {OS }}$ | Input Offset Voltage Temperature Coefficient | Measured from $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ |  | -2 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Avol | Open Loop Gain |  | 15 | 56 |  | kV/V |
| INPUT CHARACTERISTICS |  |  |  |  |  |  |
| CMIR | Common Mode Input Range | Guaranteed by CMRR test | -3.5 |  | +3.5 | V |
| CMRR | Common Mode Rejection Ratio |  | 85 | 100 |  | dB |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current |  | -100 | 20 | +100 | nA |
| los | Input Offset Current |  | -30 | 6 | 30 | nA |
| $\mathrm{R}_{\mathrm{IN}}$ | Input Resistance |  | 80 | 170 |  | $\mathrm{M} \Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance |  |  | 1 |  | pF |
| OUTPUT CHARACTERISTICS |  |  |  |  |  |  |
| V OUT | Output Voltage Swing Low | $\mathrm{R}_{\mathrm{L}}=150 \Omega$ to GND | $\pm 2.5$ | $\pm 2.8$ |  | V |
|  |  | $\mathrm{R}_{\mathrm{L}}=500 \Omega$ to GND | $\pm 3.1$ | $\pm 3.4$ |  | V |
| lout | Output Current | $R_{L}=10 \Omega$ to $G N D$ | $\pm 40$ | $\pm 70$ |  | mA |

Electrical Specifications $\quad \mathrm{V}_{\mathrm{S}^{+}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}^{-}}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=150 \Omega, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified. (Continued)

| PARAMETER | DESCRIPTION | CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ENABLE (SELECTED PACKAGES ONLY) |  |  |  |  |  |  |
| ten | Enable Time | EL5150 |  | 210 |  | ns |
| tois | Disable Time | EL5150 |  | 620 |  | ns |
| IIHCE | $\overline{\text { CE Pin Input High Current }}$ | $\overline{\mathrm{CE}}=\mathrm{V}_{\mathrm{S}^{+}}$ | 1 | 5 | 25 | $\mu \mathrm{A}$ |
| IILCE | $\overline{\text { CE Pin Input Low Current }}$ | $\overline{\mathrm{CE}}=\mathrm{V}_{\mathrm{S}^{+}}-5 \mathrm{~V}$ | -1 | 0 | +1 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {IHCE }}$ | $\overline{\mathrm{CE}}$ Input High Voltage for Powerdown | Disable | $\mathrm{V}_{\mathrm{S}^{+-1}}$ |  |  | V |
| VILCE | $\overline{\mathrm{CE}}$ Input Low Voltage for Powerdown | Enable |  |  | $\mathrm{V}_{S^{+}-3}$ | V |
| SUPPLY |  |  |  |  |  |  |
| ISON | Supply Current - Enabled (per amplifier) | No load, $\mathrm{V}_{\mathrm{IN}}=0 \mathrm{~V}, \overline{\mathrm{CE}}=+5 \mathrm{~V}$ | 1.12 | 1.35 | 1.6 | mA |
| ISOFF+ | Supply Current - Disabled (per amplifier) |  | -10 | -1 | +5 | $\mu \mathrm{A}$ |
| ISOFF- | Supply Current - Disabled (per amplifier) | No load, $\mathrm{V}^{\text {IN }}=0 \mathrm{~V}$ | -25 | -14 | 0 | $\mu \mathrm{A}$ |
| PSRR | Power Supply Rejection Ratio | $\mathrm{DC}, \mathrm{V}_{\mathrm{S}}= \pm 3.0 \mathrm{~V}$ to $\pm 6.0 \mathrm{~V}$ | 80 | 110 |  | dB |

NOTE:

1. Standard NTSC test, AC signal amplitude $=286 \mathrm{mV} \mathrm{V}_{\mathrm{P}-\mathrm{P}, \mathrm{f}} \mathrm{f}=3.58 \mathrm{MHz}, \mathrm{V}_{\mathrm{OUT}}$ is swept from 0.8 V to $3.4 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}$ is DC -coupled.

## Typical Performance Curves



FIGURE 1. EL5150 FREQUENCY vs OPEN LOOP GAIN/PHASE


FIGURE 2. PHASE vs FREQUENCY FOR VARIOUS GAINS

## Typical Performance Curves (Continued)



FIGURE 3. EL5150 GAIN vs FREQUENCY FOR VARIOUS $R_{L}$


FIGURE 5. EL5150 GAIN vs FREQUENCY FOR VARIOUS $R_{L}$


FIGURE 7. EL5150 GAIN vs FREQUENCY FOR VARIOUS $C_{L}$


FIGURE 4. EL5150 GAIN vs FREQUENCY FOR VARIOUS $R_{L}$


FIGURE 6. EL5150 GAIN vs FREQUENCY FOR VARIOUS CL


FIGURE 8. EL5150 GAIN vs FREQUENCY FOR VARIOUS CL

## Typical Performance Curves (Continued)



FIGURE 9. EL5150 GAIN vs FREQUENCY FOR VARIOUS $\mathrm{C}_{\mathrm{IN}}{ }^{-}$


FREQUENCY ( Hz )
FIGURE 11. EL5150 GAIN vs FREQUENCY FOR VARIOUS $\mathrm{C}_{\mathrm{IN}^{-}}$


FIGURE 13. EL5150 GAIN vs FREQUENCY FOR VARIOUS $\mathbf{R}_{\mathbf{F}} / \mathbf{R}_{\mathbf{G}}$


FIGURE 10. EL5150 GAIN vs FREQUENCY FOR VARIOUS $C_{I N}$


FREQUENCY (Hz)
FIGURE 12. EL5250 GAIN vs FREQUENCY FOR VARIOUS $R_{L}$


FIGURE 14. EL5250 GAIN vs FREQUENCY FOR VARIOUS GAINS

## Typical Performance Curves (Continued)



FIGURE 15. EL5250 GAIN vs FREQUENCY FOR VARIOUS GAINS


FIGURE 17. PSRR vs FREQUENCY


FIGURE 19. EL5250 CROSSTALK vs FREQUENCY


FIGURE 16. PSRR vs FREQUENCY


FIGURE 18. EL5250 CROSSTALK vs FREQUENCY


FIGURE 20. OUTPUT IMPEDANCE

## Typical Performance Curves (Continued)



FIGURE 21. CMRR


FIGURE 23. SUPPLY CURRENT vs SUPPLY VOLTAGE


FIGURE 25. DISTORTION vs OUTPUT AMPLITUDE


FIGURE 22. GROUP DELAY


FIGURE 24. VOLTAGE + CURRENT NOISE vs FREQUENCY


FIGURE 26. SLEW RATE vs POWER SUPPLY

## Typical Performance Curves (Continued)



FIGURE 27. TOTAL HARMONIC DISTORTION vs OUTPUT VOLTAGE


TIME (40ns/DIV)
FIGURE 29. SMALL SIGNAL STEP RESPONSE


TIME (40ns/DIV)
FIGURE 31. SMALL SIGNAL STEP RESPONSE


FIGURE 28. HARMONIC DISTORTION vs FREQUENCY


FIGURE 30. LARGE SIGNAL STEP RESPONSE


FIGURE 32. LARGE SIGNAL STEP RESPONSE

## Typical Performance Curves (Continued)



TIME (400ns/DIV)
FIGURE 33. EL5150 ENABLE/DISABLE


FIGURE 35. DIFFERENTIAL GAIN


FIGURE 37. SMALL SIGNAL FREQUENCY vs SUPPLY


TIME ( $1 \mu \mathrm{~L} / \mathrm{DIV}$ )
FIGURE 34. EL5250 ENABLE/DISABLE


FIGURE 36. DIFFERENTIAL PHASE


FIGURE 38. INPUT-TO-OUTPUT ISOLATION WITH PART DISABLED

## Typical Performance Curves (Continued)



FIGURE 39. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

## Product Description

The EL5150, EL5151, EL5250, EL5251 and EL5451 are wide bandwidth, low power, low offset voltage feedback operational amplifiers capable of operating from a single or dual power supplies. This family of operational amplifiers are internally compensated for closed loop gain of +1 or greater. Connected in voltage follower mode, driving a $500 \Omega$ load members of this amplifier family demonstrate a -3dB bandwidth of about 200 MHz . With the loading set to accommodate typical video application, $150 \Omega$ load and gain set to +2 , bandwidth reduces to about 40 MHz with a $67 \mathrm{~V} / \mu \mathrm{s}$ slew rate. Power down pins on the EL5151 and EL5251 reduce the already low power demands of this amplifier family to $12 \mu \mathrm{~A}$ typical while the amplifier is disabled.

## Input, Output and Supply Voltage Range

The EL5150 and family members have been designed to operate with supply voltage ranging from 5 V to 12 V . Supply voltages range from $\pm 2.5 \mathrm{~V}$ to $\pm 5 \mathrm{~V}$ for split supply operation. And of course split supply operation can easily be achieved using single supplies with by splitting off half of the single supply with a simple voltage divider as illustrated in the application circuit section.

## Input Common Mode Range

These amplifiers have an input common mode voltage ranging from 3.5 V above the negative supply $\left(\mathrm{V}_{\mathrm{S}^{-}} \mathrm{pin}\right)$ to 3.5 V below the positive supply $\left(\mathrm{V}_{\mathrm{S}^{+}}\right.$pin). If the input signal is driven beyond this range the output signal will exhibit distortion.

## Maximum Output Swing \& Load Resistance

The outputs of the EL5150 and family members exhibit maximum output swing ranges from -4 V to 4 V for $\mathrm{V}_{\mathrm{S}}= \pm 5 \mathrm{~V}$ with a load resistance of $500 \Omega$. Naturally, as the load resistance becomes lower, the output swing lowers


FIGURE 40. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE
accordingly; for instance, if the load resistor is $150 \Omega$, the output swing ranges from -3.5 V to 3.5 V . This response is a simple application of Ohms law indicating a lower value resistance results in greater current demands of the amplifier. Additionally, the load resistance affects the frequency response of this family as well as all operational amplifiers; as clearly indicated by the Gain vs Frequency For Various $R_{L}$ curves clearly indicate. In the case of the frequency response reduced bandwidth with decreasing load resistance is a function of load resistance in conjunction with the output zero response of the amplifier.

## Choosing A Feedback Resistor

A feedback resistor is required to achieve unity gain; simply short the output pin to the inverting input pin. Gains greater than +1 require a feedback and gain resistor to set the desired gain. This gets interesting because the feedback resistor forms a pole with the parasitic capacitance at the inverting input; as the feedback resistance increases the position of the pole shifts in the frequency domain, the amplifier's phase margin is reduced and the amplifier becomes less stable. Peaking in the frequency domain and ringing in the time domain are symptomatic of this shift in pole location. So we want to keep the feedback resistor as small as possible. You may want to use a large feedback resistor for some reason; in this case to compensate the shift of the pole and maintain stability a small capacitor in the few Pico farad range in parallel with the feedback resistor is recommended.

For the gains greater than unity it has been determined a feedback resistance ranging from $500 \Omega$ to $750 \Omega$ provides optimal response.

## Gain Bandwidth Product

The EL5150 and family members have a gain bandwidth product of 40 MHz for a gain of +5 . Bandwidth can be predicted by the following equation:
(Gain) $\times(B W)=$ GainBandwidthProduct

## Video Performance

For good video performance, an amplifier is required to maintain the same output impedance and same frequency response as DC levels are changed at the output; this characteristic is widely referred to as "diffgain-diffphase". Many amplifiers have a difficult time with this especially while driving standard video loads of $150 \Omega$, as the output current has a natural tendency to change with DC level. The dG and dP for these families is a respectable $0.04 \%$ and $0.9^{\circ}$, while driving $150 \Omega$ at a gain of 2 . Driving high impedance loads would give a similar or better dG and dP performance as the current output demands placed on the amplifier lessen with increased load.

## Driving Capacitive Loads

These devices can easily drive capacitive loads as demanding as 27 pF in parallel with $500 \Omega$ while holding peaking to within 5 dB of peaking at unity gain. Of course if less peaking is desired, a small series resistor (usually between $5 \Omega$ to $50 \Omega$ ) can be placed in series with the output to eliminate most peaking; however, there will be a small sacrifice of gain which can be recovered by simply adjusting the value of the gain resistor.

## Driving Cables

Both ends of all cables must always be properly terminated; double termination is absolutely necessary for reflection-free performance. Additionally, a back-termination series resistor at the amplifier's output will isolate the amplifier from the cable and allow extensive capacitive drive. However, other applications may have high capacitive loads without a back-termination resistor. Again, a small series resistor at the output can help to reduce peaking.

## Disable/Power-Down

Devices with disable can be disabled with their output placed in a high impedance state. The turn off time is about 330ns and the turn on time is about 130 ns . When disabled, the amplifier's supply current is reduced to $17 \mu \mathrm{~A}$ typically; essentially eliminating power consumption. The amplifier's power down is controlled by standard TTL or CMOS signal levels at the ENABLE pin. The applied logic signal is relative to $\mathrm{V}_{\mathrm{S}^{-}}$pin. Letting the ENABLE pin float or the application of a signal that is less than 0.8 V above $\mathrm{V}_{\mathrm{S}^{-}}$enables the amplifier. The amplifier is disabled when the signal at ENABLE pin is above $\mathrm{V}_{\mathrm{S}^{+}}-1.5 \mathrm{~V}$.

## Output Drive Capability

Members of the EL5150 family do not have internal short circuit protection circuitry. Typically, short circuit currents
ranging from 70 mA and 95 mA can be expected and naturally, if the output is shorted indefinitely the part can easily be damaged from overheating; or excessive current density may eventually compromise metal integrity. Maximum reliability is maintained if the output current is always held below $\pm 40 \mathrm{~mA}$. This limit is set and limited by the design of the internal metal interconnect. Note that in transient applications, the part is extremely robust.

## Power Dissipation

With the high output drive capability of these devices, it is possible to exceed the $+125^{\circ} \mathrm{C}$ absolute maximum junction temperature under certain load current conditions.
Therefore, it is important to calculate the maximum junction temperature for an application to determine if load conditions or package types need to be modified to assure operation of the amplifier in a safe operating area.
The maximum power dissipation allowed in a package is determined according to Equation 1:

$$
\begin{equation*}
\mathrm{PD}_{\mathrm{MAX}}=\frac{\mathrm{T}_{\mathrm{JMAX}}-\mathrm{T}_{\mathrm{AMAX}}}{\Theta_{J A}} \tag{EQ.1}
\end{equation*}
$$

Where:
$T_{J M A X}=$ Maximum junction temperature
$\mathrm{T}_{\text {AMAX }}=$ Maximum ambient temperature
$\theta_{\mathrm{JA}}=$ Thermal resistance of the package
The maximum power dissipation actually produced by an IC is the total quiescent supply current times the total power supply voltage, plus the power in the IC due to the load, or:
For sourcing:

$$
\begin{equation*}
\mathrm{PD}_{\mathrm{MAX}}=\mathrm{V}_{\mathrm{S}} \times \mathrm{I}_{\mathrm{SMAX}}+\sum_{i=1}^{n}\left(\mathrm{~V}_{\mathrm{S}}-\mathrm{V}_{\text {OUTi }}\right) \times \frac{\mathrm{V}_{\text {OUTi }}}{R_{\mathrm{Li}}} \tag{EQ.2}
\end{equation*}
$$

For sinking:
$P D_{\text {MAX }}=V_{S} \times I_{S M A X}+\sum_{i=1}^{n}\left(V_{\text {OUTi }}-V_{S}\right) \times I_{\text {LOADi }}$
Where:
$\mathrm{V}_{\mathrm{S}}=$ Supply voltage
ISMAX $=$ Maximum quiescent supply current
$\mathrm{V}_{\text {OUT }}=$ Maximum output voltage of the application
R LOAD $=$ Load resistance tied to ground
LLOAD = Load current
$\mathrm{N}=$ number of amplifiers $(\mathrm{Max}=2)$
By setting the two $P_{\text {MAX }}$ equations equal to each other, we can solve the output current and R ROAD to avoid the device overheat.

## Power Supply Bypassing Printed Circuit Board Layout

As with any high frequency device, a good printed circuit board layout is necessary for optimum performance. Lead lengths should be as short as possible. The power supply pin must be well bypassed to reduce the risk of oscillation. For normal single supply operation, where the $\mathrm{V}_{\mathrm{S}^{-}}$pin is connected to the ground plane, a single $4.7 \mu \mathrm{~F}$ tantalum capacitor in parallel with a $0.1 \mu \mathrm{~F}$ ceramic capacitor from $\mathrm{V}_{\mathrm{S}^{+}}$ to GND will suffice. This same capacitor combination should be placed at each supply pin to ground if split supplies are to be used. In this case, the $\mathrm{V}_{\mathrm{S}^{-}}$pin becomes the negative supply rail.

## Printed Circuit Board Layout

For good AC performance, parasitic capacitance should be kept to a minimum. Use of wire wound resistors should be avoided because of their additional series inductance. Use of sockets should also be avoided if possible. Sockets add parasitic inductance and capacitance that can result in
compromised performance. Minimizing parasitic capacitance at the amplifier's inverting input pin is very important. The feedback resistor should be placed very close to the inverting input pin. Strip line design techniques are recommended for the signal traces.

## Application Circuits

## Sallen Key Low Pass Filter

A common and easy to implement filter taking advantage of the wide bandwidth, low offset and low power demands of the EL5150. A derivation of the transfer function is provided for convenience (see Figure 41).

## Sallen Key High Pass Filter

Again, this useful filter benefits from the characteristics of the EL5150. The transfer function is very similar to the low pass so only the results are presented (see Figure 42).


$$
\begin{aligned}
& \mathrm{K}=1+\frac{\mathrm{RB}}{\mathrm{RA}} \\
& \mathrm{Vo}_{0}=\mathrm{K} \frac{1}{\mathrm{R} 2 \mathrm{C} 2 \mathrm{~s}+1} \mathrm{~V}_{1} \\
& \frac{\mathrm{~V}_{1}-\mathrm{Vi}_{\mathrm{i}}}{\mathrm{R} 1} 1+\frac{\frac{\mathrm{V} 0}{\mathrm{~K}-\mathrm{V}_{1}}}{\mathrm{R} 2}+\frac{\mathrm{Vo}_{0}-\mathrm{Vi}^{2}}{\frac{1}{\mathrm{C} 1 \mathrm{~s}}}=0
\end{aligned}
$$

$$
H(s)=\frac{K}{R_{1} C 1 R 2 C 2 s^{2}+((1-K) R 1 C 1+R 1 C 2+R 21 C 2) s+1}
$$

$$
H(j w)=\frac{1}{1-w^{2} R 1 C 1 R 2 C 2+j w((1-K) R 1 C 1+R 1 C 2+R 2 C 2)}
$$

Holp $=$ K

$$
\text { wo }=\frac{1}{\sqrt{\text { R1C1R2C2 }}}
$$

$$
\mathrm{Q}=\frac{1}{(1-\mathrm{K}) \sqrt{\frac{\mathrm{R} 1 \mathrm{C} 1}{\mathrm{R} 2 \mathrm{C} 2}}+\sqrt{\frac{\mathrm{R} 1 \mathrm{C} 2}{\mathrm{R} 2 \mathrm{C} 1}}+\sqrt{\frac{\mathrm{R} 2 \mathrm{C} 2}{\mathrm{R} 1 \mathrm{C} 1}}}
$$

$$
\begin{array}{ll}
\text { Holp }=K & \text { Equations simplify if we let all } \\
\text { wo }=\frac{1}{R C} & \text { components be equal } R=C \\
Q=\frac{1}{3-K} &
\end{array}
$$

FIGURE 41. SALLEN KEY LOW PASS FILTER


FIGURE 42. SALLEN KEY HIGH PASS FILTER

## Differential Output Instrumentation Amplifier

The addition of a third amplifier to the conventional three amplifier Instrumentation Amplifier introduces the benefits of differential signal realization; specifically the advantage of using common mode rejection to remove coupled noise and ground -potential errors inherent in remote transmission. This configuration also provides enhanced bandwidth, wider output swing and faster slew rate than conventional three amplifier solutions with only the cost of an additional amplifier and few resistors.


## Strain Gauge

The strain gauge is an ideal application to take advantage of the moderate bandwidth and high accuracy of the EL5150. The operation of the circuit is very straight-forward. As the strain variable component resistor in the balanced bridge is subjected to increasing strain, its resistance changes
resulting in an imbalance in the bridge. A voltage variation from the referenced high accuracy source is generated and translated to the difference amplifier through the buffer stage. This voltage difference as a function of the strain is converted into an output voltage.


## Small Outline Package Family (SO)






DETAIL X

MDP0027
SMALL OUTLINE PACKAGE FAMILY (SO)

| SYMBOL | INCHES |  |  |  |  |  |  | TOLERANCE | NOTES |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | SO-8 | SO-14 | $\begin{gathered} \text { SO16 } \\ (0.150 ") \end{gathered}$ | $\begin{gathered} \text { SO16 (0.300") } \\ \text { (SOL-16) } \end{gathered}$ | $\begin{gathered} \text { SO20 } \\ \text { (SOL-20) } \end{gathered}$ | $\begin{gathered} \text { SO24 } \\ (\mathrm{SOL}-24) \end{gathered}$ | $\begin{gathered} \text { SO28 } \\ \text { (SOL-28) } \end{gathered}$ |  |  |
| A | 0.068 | 0.068 | 0.068 | 0.104 | 0.104 | 0.104 | 0.104 | MAX | - |
| A1 | 0.006 | 0.006 | 0.006 | 0.007 | 0.007 | 0.007 | 0.007 | $\pm 0.003$ | - |
| A2 | 0.057 | 0.057 | 0.057 | 0.092 | 0.092 | 0.092 | 0.092 | $\pm 0.002$ | - |
| b | 0.017 | 0.017 | 0.017 | 0.017 | 0.017 | 0.017 | 0.017 | $\pm 0.003$ | - |
| c | 0.009 | 0.009 | 0.009 | 0.011 | 0.011 | 0.011 | 0.011 | $\pm 0.001$ | - |
| D | 0.193 | 0.341 | 0.390 | 0.406 | 0.504 | 0.606 | 0.704 | $\pm 0.004$ | 1,3 |
| E | 0.236 | 0.236 | 0.236 | 0.406 | 0.406 | 0.406 | 0.406 | $\pm 0.008$ | - |
| E1 | 0.154 | 0.154 | 0.154 | 0.295 | 0.295 | 0.295 | 0.295 | $\pm 0.004$ | 2, 3 |
| e | 0.050 | 0.050 | 0.050 | 0.050 | 0.050 | 0.050 | 0.050 | Basic | - |
| L | 0.025 | 0.025 | 0.025 | 0.030 | 0.030 | 0.030 | 0.030 | $\pm 0.009$ | - |
| L1 | 0.041 | 0.041 | 0.041 | 0.056 | 0.056 | 0.056 | 0.056 | Basic | - |
| h | 0.013 | 0.013 | 0.013 | 0.020 | 0.020 | 0.020 | 0.020 | Reference | - |
| N | 8 | 14 | 16 | 16 | 20 | 24 | 28 | Reference | - |

NOTES:
Rev. M 2/07

1. Plastic or metal protrusions of 0.006 " maximum per side are not included.
2. Plastic interlead protrusions of 0.010 " maximum per side are not included.
3. Dimensions "D" and "E1" are measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994

## SOT-23 Package Family



## MDP0038

SOT-23 PACKAGE FAMILY

| SYMBOL | MILLIMETERS |  |  |
| :---: | :---: | :---: | :---: |
|  | SOT23-5 | SOT23-6 |  |
| A | 1.45 | 1.45 | MAX |
| A1 | 0.10 | 0.10 | $\pm 0.05$ |
| A2 | 1.14 | 1.14 | $\pm 0.15$ |
| b | 0.40 | 0.40 | $\pm 0.05$ |
| c | 0.14 | 0.14 | $\pm 0.06$ |
| D | 2.90 | 2.90 | Basic |
| E | 2.80 | 2.80 | Basic |
| E1 | 1.60 | 1.60 | Basic |
| e | 0.95 | 0.95 | Basic |
| e1 | 1.90 | 1.90 | Basic |
| L | 0.45 | 0.45 | $\pm 0.10$ |
| L1 | 0.60 | 0.60 | Reference |
| N | 5 | 6 | Reference |
|  |  |  |  |
|  |  |  |  |

NOTES:

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.
3. This dimension is measured at Datum Plane " $H$ ".
4. Dimensioning and tolerancing per ASME Y14.5M-1994.
5. Index area - Pin \#1 I.D. will be located within the indicated zone (SOT23-6 only).
6. SOT23-5 version has no center lead (shown as a dashed line).

## Mini SO Package Family (MSOP)



DETAIL X

MDP0043
MINI SO PACKAGE FAMILY

| SYMBOL | MILLIMETERS |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MSOP8 | MSOP10 | TOLERANCE |  |
| A | 1.10 | 1.10 | Max. | - |
| A1 | 0.10 | 0.10 | $\pm 0.05$ | - |
| A2 | 0.86 | 0.86 | $\pm 0.09$ | - |
| b | 0.33 | 0.23 | $+0.07 /-0.08$ | - |
| c | 0.18 | 0.18 | $\pm 0.05$ | - |
| D | 3.00 | 3.00 | $\pm 0.10$ | 1,3 |
| E | 4.90 | 4.90 | $\pm 0.15$ | - |
| E1 | 3.00 | 3.00 | $\pm 0.10$ | 2,3 |
| e | 0.65 | 0.50 | Basic | - |
| L | 0.55 | 0.55 | $\pm 0.15$ | - |
| L1 | 0.95 | 0.95 | Basic | - |
| N | 8 | 10 | Reference | - |

Rev. D 2/07
NOTES:

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.
3. Dimensions "D" and "E1" are measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994.

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